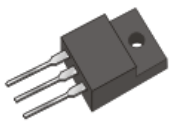
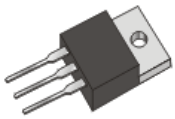
PJP10NA80 / PJF10NA80

800V N-Channel MOSFET

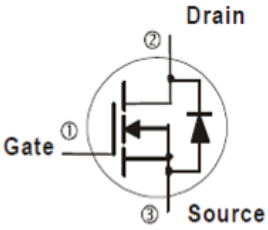
Voltage	800 V	Current	10 A



ITO-220AB-F



TO-220AB



Features

- $R_{DS(ON)}$, V_{GS}@10V,I_D@ 5A<1.15Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: TO-220AB, ITO-220AB-F Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-220AB Approx. Weight : 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	UNITS
Drain-Source Voltage		V_{DS}	800		V
Gate-Source Voltage		V_{GS}	±30		V
Continuous Drain Current		I_D	10		A
Pulsed Drain Current		I_{DM}	40		A
Single Pulse Avalanche Energy (Note 1)		E_{AS}	795		mJ
Power Dissipation	T_C=25°C	P_D	180	60	W
	Derate above 25°C		1.44	0.48	W/°C
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150		°C
Typical Thermal resistance					
- Junction to Case		$R_{\theta JC}$	0.69	2.08	°C/W
- Junction to Ambient		$R_{\theta JA}$	62.5	120	

- Limited only By Maximum Junction Temperature

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V,I_D=250uA	800	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS},I_D=250uA	2	3	4	V
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=10V,I_D=5A	-	1.05	1.15	Ω
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=800V,V_{GS}=0V	-	0.01	1	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±30V,V_{DS}=0V	-	±10	±100	nA
Diode Forward Voltage	V_{SD}	I_S=10A,V_{GS}=0V	-	0.87	1.4	V
Dynamic (Note 4)						
Total Gate Charge	Q_g	V_{DS}=640V, I_D=10A, V_{GS}=10V (Note 2,3)	-	31	-	nC
Gate-Source Charge	Q_{gs}		-	8	-	
Gate-Drain Charge	Q_{gd}		-	12	-	
Input Capacitance	Ciss	V_{DS}=25V, V_{GS}=0V, f=1.0MHZ	-	1517	-	pF
Output Capacitance	Coss		-	180	-	
Reverse Transfer Capacitance	Crss		-	9	-	
Turn-On Delay Time	$td_{(on)}$	V_{DD}=400V, I_D=10A, R_G=25Ω (Note 2,3)	-	22	-	ns
Turn-On Rise Time	t_r		-	31	-	
Turn-Off Delay Time	$td_{(off)}$		-	56	-	
Turn-Off Fall Time	t_f		-	31	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	10	A
Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}	---	-	-	40	A
Reverse Recovery Time	trr	V_{GS}=0V, I_S=10A dI_F/ dt=100A/us (Note 2)	-	660	-	ns
Reverse Recovery Charge	Qrr		-	6	-	uC

NOTES :

1. L=30mH, I_{AS}=7.1A, V_{DD}=50V, R_G=25 ohm, Starting T_J=25°C
2. Pulse width≤300us, Duty cycle≤2%
3. Essentially independent of operating temperature typical characteristics.
4. Guaranteed by design, not subject to production testing

PJP10NA80 / PJF10NA80

TYPICAL CHARACTERISTIC CURVES

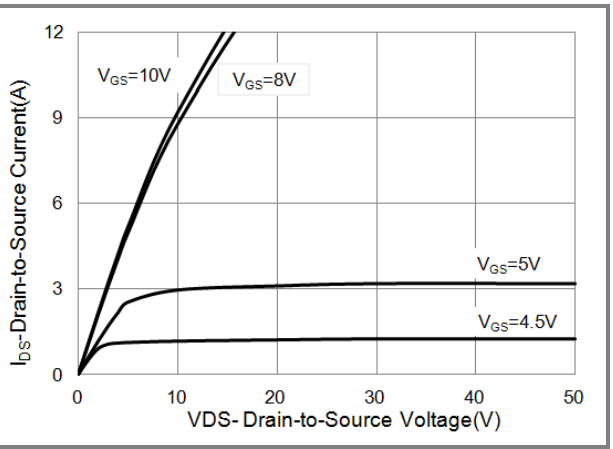

Fig.1 Output Characteristics

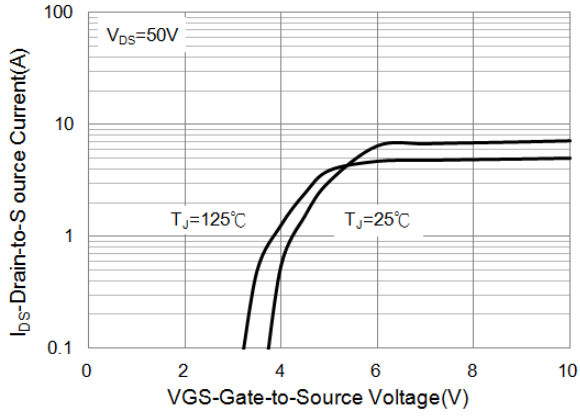

Fig.2 Transfer Characteristics

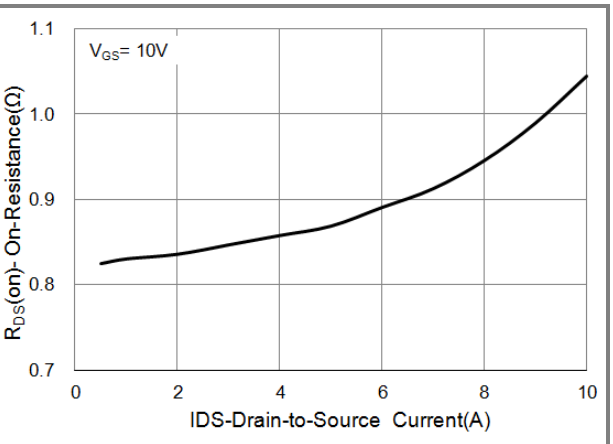

Fig.3 On-Resistance vs. Drain Current

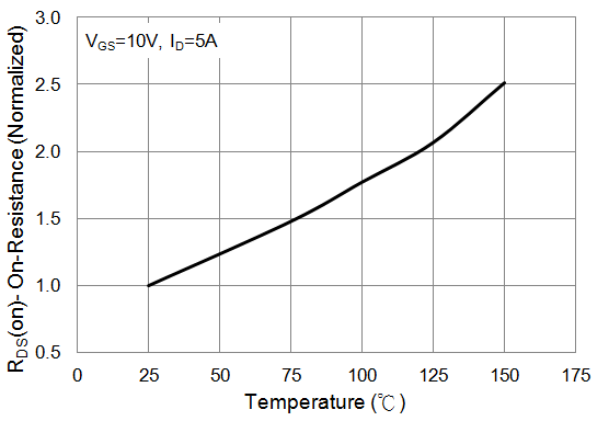

Fig.4 On-Resistsnce vs. Junction temperature

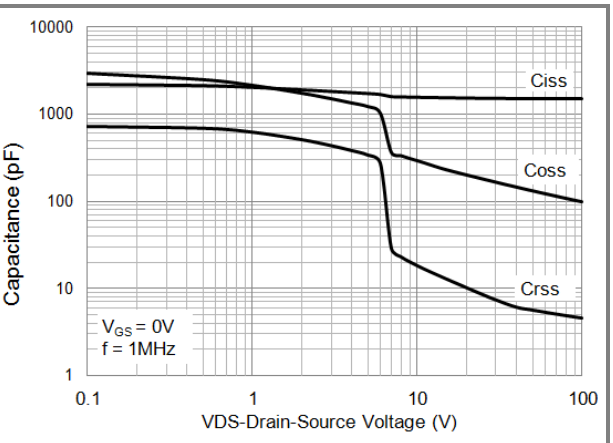

Fig.5 Capacitance vs. Drain-Source Voltage

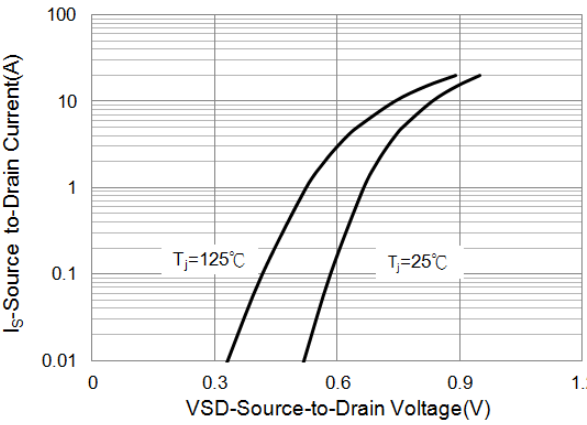

Fig.6 Body Diode CharacterIsIcs

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TYPICAL CHARACTERISTIC CURVES

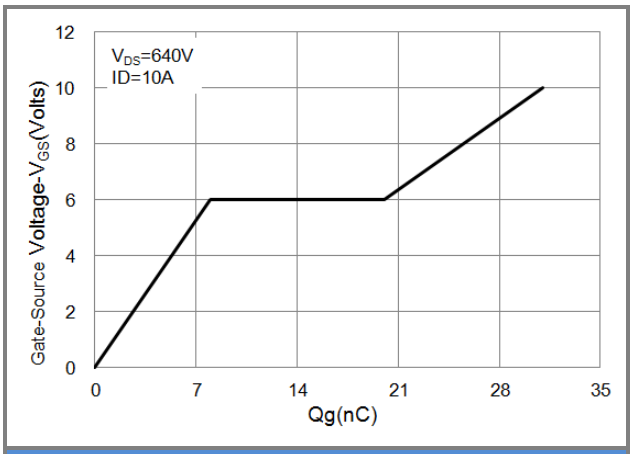

Fig.7 Gate-Charge Characteristics

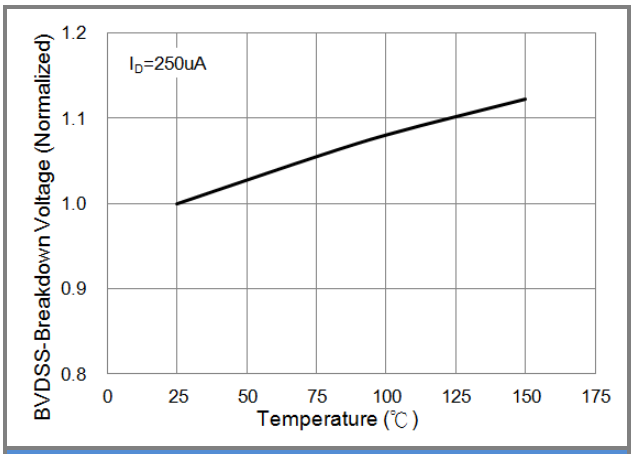

Fig.8 Breakdown Voltage Variation vs.Temperature

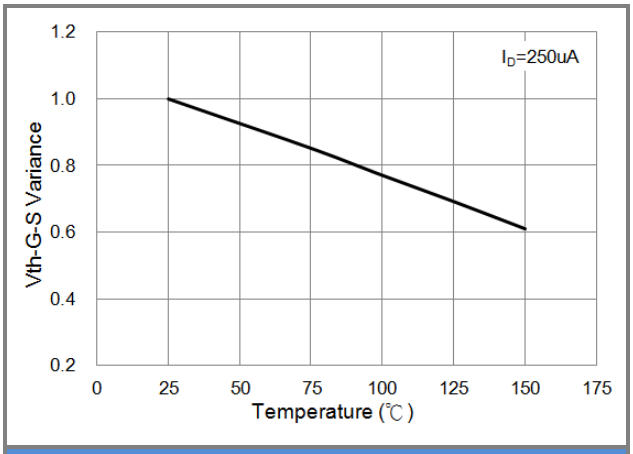

Fig.9 Threshold Voltage Variation with Temperature

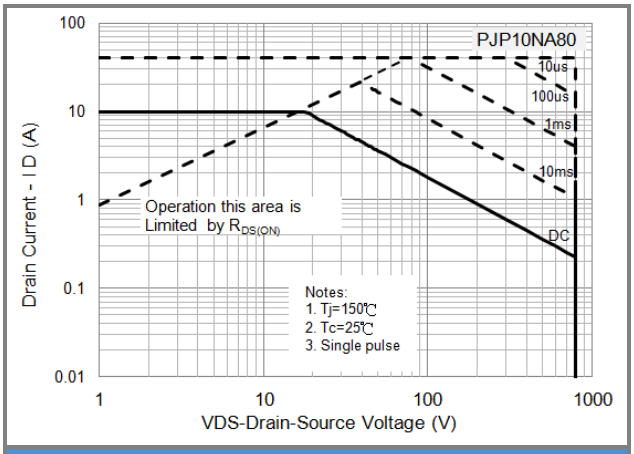

Fig.10 Maximum Safe Operating Area

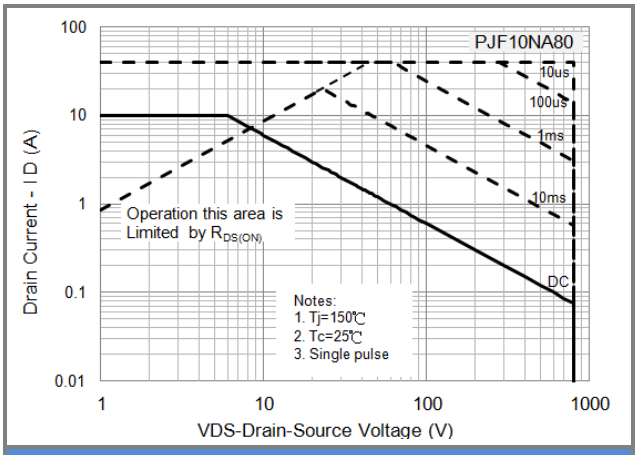

Fig.11 Maximum Safe Operating Area

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TYPICAL CHARACTERISTIC CURVES

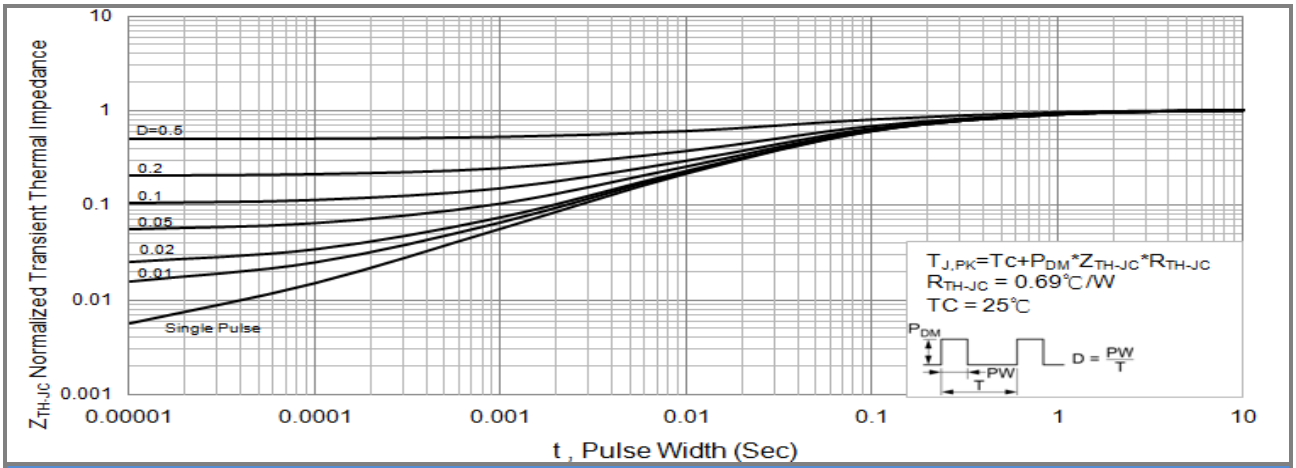


Fig.13 PJP10NA80 Normalized Transient Thermal Impedance vs. Pulse Width

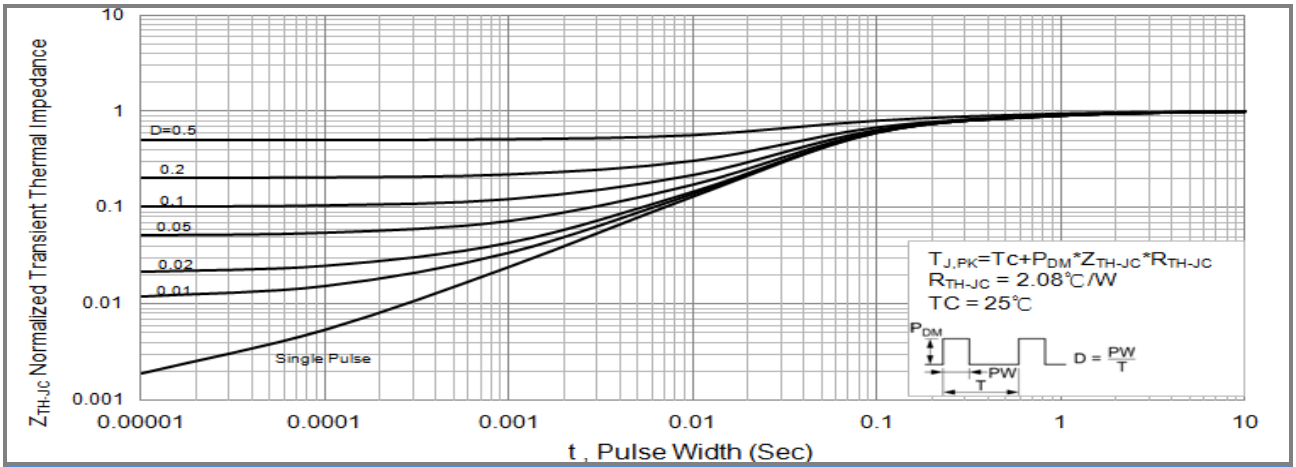


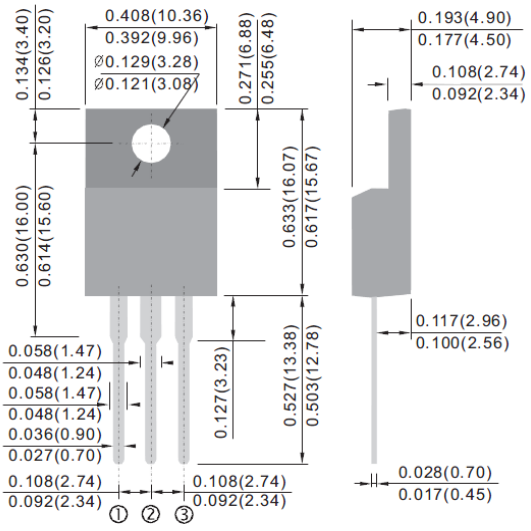
Fig.14 PJF10NA80 Normalized Transient Thermal Impedance vs. Pulse Width

PJP10NA80 / PJF10NA80

Packaging Information .

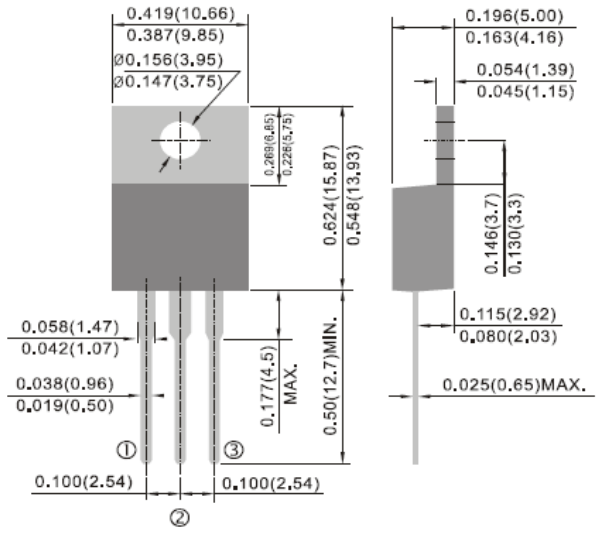
ITO-220AB-F Dimension

Unit: mm



TO-220AB Dimension

Unit: mm



PJP10NA80 / PJF10NA80

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJP10NA80_T0_00001	TO-220AB	50pcs / Tube	P10NA80	Halogen free
PJF10NA80_T0_00001	ITO-220AB-F	50pcs / Tube	F10NA80	Halogen free

PJP10NA80 / PJF10NA80

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